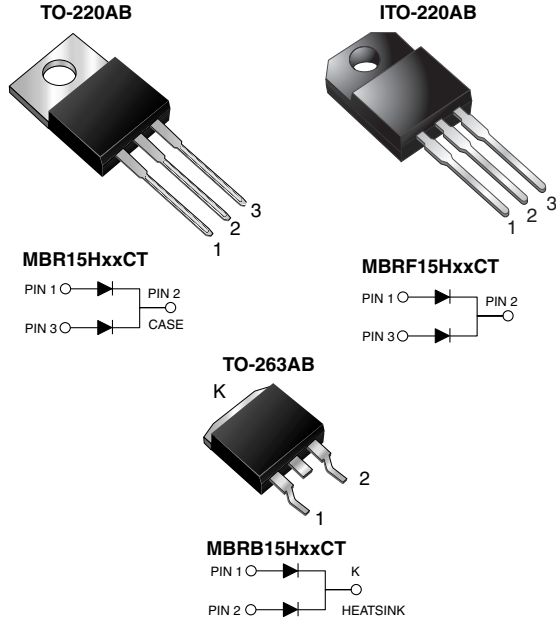


Dual Common Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



FEATURES

- Power pack
- Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating
 Base P/N-E3 - RoHS-compliant, commercial grade
 Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102
 E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 7.5 A
V_{RRM}	35 V to 60 V
I_{FSM}	150 A
V_F	0.55 V, 0.61 V
I_R	50 μ A
T_J max.	175 °C
Package	TO-220AB, ITO-220AB, TO-263AB
Diode variations	Common cathode



MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR15H35CT	MBR15H45CT	MBR15H50CT	MBR15H60CT	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	35	45	50	60	V
Working peak reverse voltage	V _{RWM}	35	45	50	60	
Maximum DC blocking voltage	V _{DC}	35	45	50	60	
Maximum average forward rectified current (fig. 1) total device per diode	I _{F(AV)}	15				A
		7.5				
Non-repetitive avalanche energy at 25 °C, I _{AS} = 4 A, L = 10 mH per diode	E _{AS}	80				mJ
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150				A
Peak repetitive reverse surge current per diode at t _p = 2.0 μs, 1 kHz	I _{RRM}	1.0		0.5		
Peak non-repetitive reverse energy (8/20 μs waveform)	E _{RSM}	20		10		mJ
Electrostatic discharge capacitor voltage Human body model: C = 100 F, R = 1.5 kΩ	V _C	25				kV
Voltage rate of change (rated V _R)	dV/dt	10 000				V/μs
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to +175				°C
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500				V

ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS	MBR15H35CT MBR15H45CT		MBR15H50CT MBR15H60CT		UNIT	
			TYP.	MAX.	TYP.	MAX.		
Maximum instantaneous forward voltage per diode	V _F ⁽¹⁾	I _F = 7.5 A T _J = 25 °C	-	0.63	-	0.73	V	
		I _F = 7.5 A T _J = 125 °C	0.50	0.55	0.58	0.61		
		I _F = 15 A T _J = 25 °C	-	0.75	-	0.87		
		I _F = 15 A T _J = 125 °C	0.61	0.66	0.68	0.72		
Maximum reverse current per diode	I _R ⁽²⁾	Rated V _R	T _J = 25 °C	-	50	-	50	μA
			T _J = 125 °C	3.0	10	2.0	10	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Maximum thermal resistance per diode	R _{θJC}	3.0	5.0	3.0	°C/W

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	MBR15H45CT-E3/45	1.85	45	50/tube	Tube
ITO-220AB	MBRF15H45CT-E3/45	1.99	45	50/tube	Tube
TO-263AB	MBRB15H45CT-E3/45	1.35	45	50/tube	Tube
TO-263AB	MBRB15H45CT-E3/81	1.35	81	800/reel	Tape and reel
TO-220AB	MBR15H45CTHE3/45 ⁽¹⁾	1.85	45	50/tube	Tube
ITO-220AB	MBRF15H45CTHE3/45 ⁽¹⁾	1.99	45	50/tube	Tube
TO-263AB	MBRB15H45CTHE3/45 ⁽¹⁾	1.35	45	50/tube	Tube
TO-263AB	MBRB15H45CTHE3/81 ⁽¹⁾	1.35	81	800/reel	Tape and reel

Note

- (1) AEC-Q101 qualified



RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

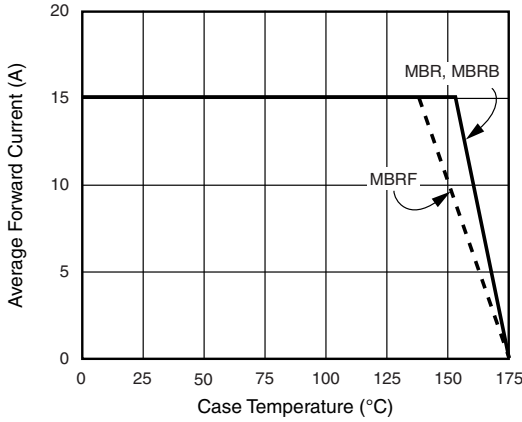


Fig. 1 - Forward Derating Curve Per Diode

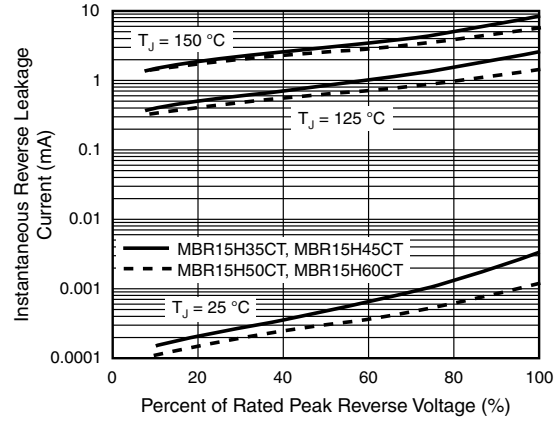


Fig. 4 - Typical Reverse Characteristics Per Diode

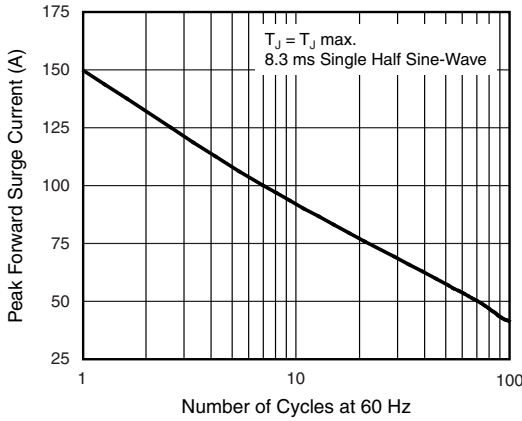


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

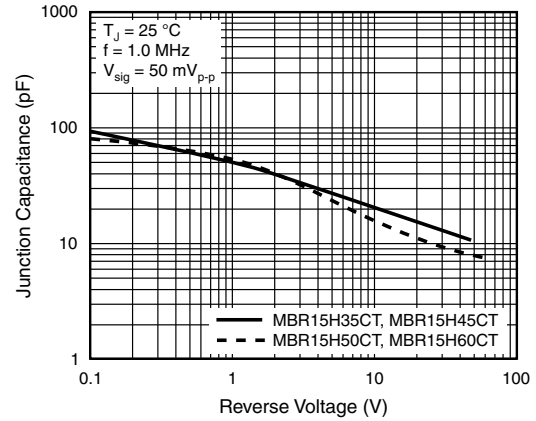


Fig. 5 - Typical Junction Capacitance Per Diode

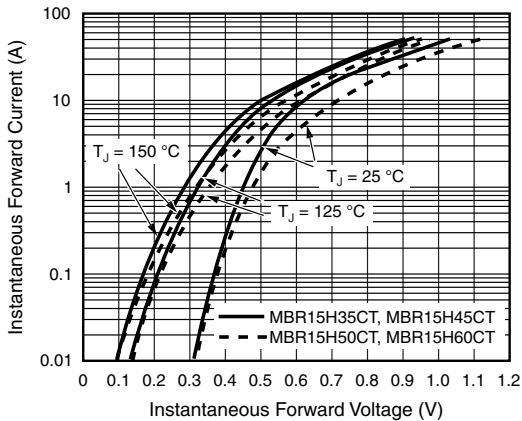


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

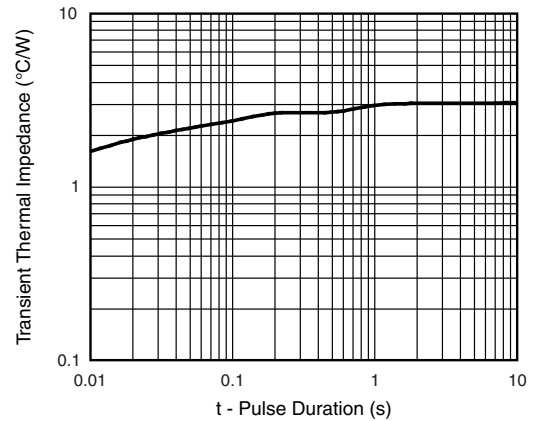
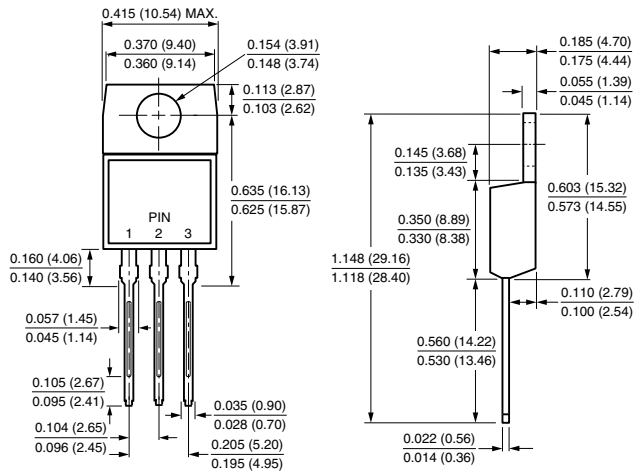


Fig. 6 - Typical Transient Thermal Impedance Per Diode

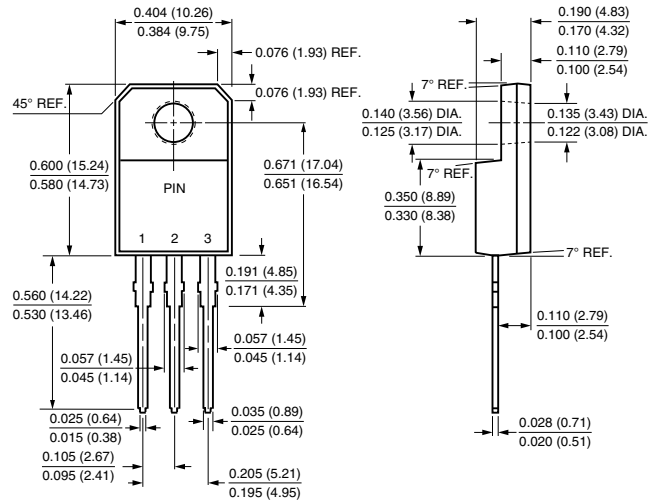


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

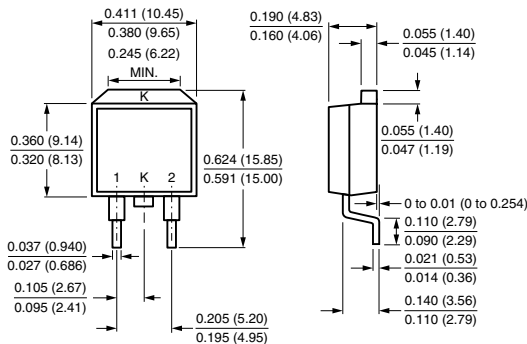
TO-220AB



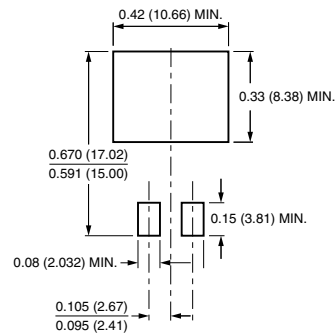
ITO-220AB



TO-263AB



Mounting Pad Layout





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